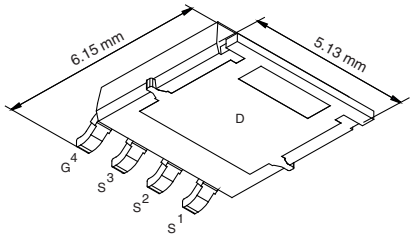
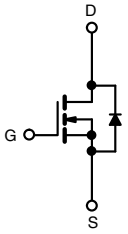
Automotive N-Channel 40 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	40
$R_{DS(on)}$ (Ω) at V_{GS} = 10 V	0.0045
$R_{DS(on)}$ (Ω) at V_{GS} = 4.5 V	0.0055
I_D (A)	60
Configuration	Single

PowerPAK® SO-8L Single





N-Channel MOSFET

FEATURES

- TrenchFET® Power MOSFET
- AEC-Q101 Qualified[c]
- 100 % R_g and UIS Tested
- Material categorization:
  For definitions of compliance please see www.vishay.com/doc?99912

AUTOMOTIVE GRADE

Pb-free

RoHS COMPLIANT

HALOGEN FREE

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and Halogen-free	SQJ886EP-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	40	V
Gate-Source Voltage		V_{GS}	± 20	
Continuous Drain Current	T_C = 25 °C	I_D	60	A
	T_C = 125 °C		45	
Continuous Source Current (Diode Conduction)		I_S	50	
Pulsed Drain Current[a]		I_{DM}	240	
Single Pulse Avalanche Current	L = 0.1 mH	I_{AS}	36	
Single Pulse Avalanche Energy		E_{AS}	64	mJ
Maximum Power Dissipation[a]	T_C = 25 °C	P_D	55	W
	T_C = 125 °C		18	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to + 175	°C
Soldering Recommendations (Peak Temperature)[d, e]			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount[b]	R_{thJA}	70	°C/W
Junction-to-Case (Drain)		R_{thJC}	2.7	

Notes

a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. When mounted on 1" square PCB (FR-4 material).
c. Parametric verification ongoing.
d. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

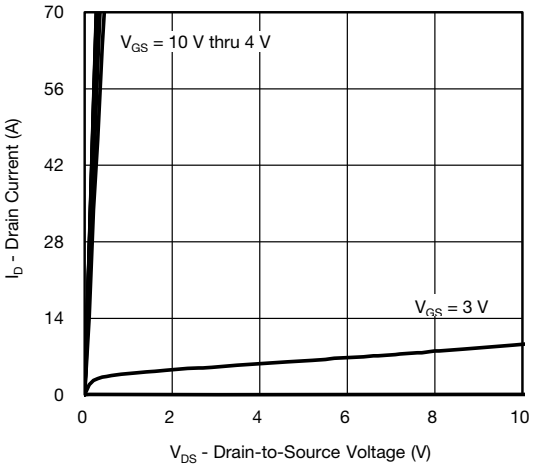
SPECIFICATIONS (T_C = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0, I_D = 250 µA		40	-	-	V
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		1.5	2.0	2.5	
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V		-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{GS} = 0 V	V_{DS} = 40 V	-	-	1	µA
		V_{GS} = 0 V	V_{DS} = 40 V, T_J = 125 °C	-	-	50	
		V_{GS} = 0 V	V_{DS} = 40 V, T_J = 175 °C	-	-	250	
On-State Drain Current[a]	$I_{D(on)}$	V_{GS} = 10 V	V_{DS} ≥ 5 V	30	-	-	A
Drain-Source On-State Resistance[a]	$R_{DS(on)}$	V_{GS} = 10 V	I_D = 15.3 A	-	0.0036	0.0045	Ω
		V_{GS} = 4.5 V	I_D = 13.8 A	-	0.0045	0.0055	
		V_{GS} = 10 V	I_D = 15.3 A, T_J = 125 °C	-	-	0.0072	
		V_{GS} = 10 V	I_D = 15.3 A, T_J = 175 °C	-	-	0.0088	
Forward Transconductance[b]	g_{fs}	V_{DS} = 15 V, I_D = 15.3 A		-	105	-	S
Dynamic[b]							
Input Capacitance	C_{iss}	V_{GS} = 0 V	V_{DS} = 20 V, f = 1 MHz	-	2338	2922	pF
Output Capacitance	C_{oss}			-	356	445	
Reverse Transfer Capacitance	C_{rss}			-	147	184	
Total Gate Charge[c]	Q_g	V_{GS} = 10 V	V_{DS} = 20 V, I_D = 20 A	-	43	65	nC
Gate-Source Charge[c]	Q_{gs}			-	8	-	
Gate-Drain Charge[c]	Q_{gd}			-	7	-	
Gate Resistance	R_g	f = 1 MHz		1.25	2.45	5	Ω
Turn-On Delay Time[c]	$t_{d(on)}$	V_{DD} = 20 V, R_L = 2 Ω I_D ≅ 10 A, V_{GEN} = 10 V, R_g = 1 Ω		-	8	12	ns
Rise Time[c]	t_r			-	17	25	
Turn-Off Delay Time[c]	$t_{d(off)}$			-	29	44	
Fall Time[c]	t_f			-	6	9	
Source-Drain Diode Ratings and Characteristics[b]							
Pulsed Current[a]	I_{SM}			-	-	240	A
Forward Voltage	V_{SD}	I_F = 10.1 A, V_{GS} = 0		-	0.8	1.2	V

Notes

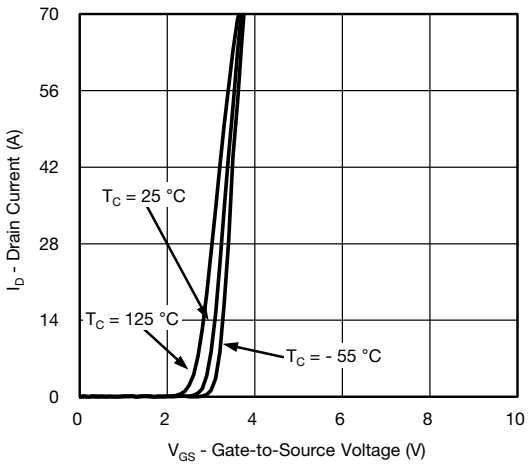
a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
b. Guaranteed by design, not subject to production testing.
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

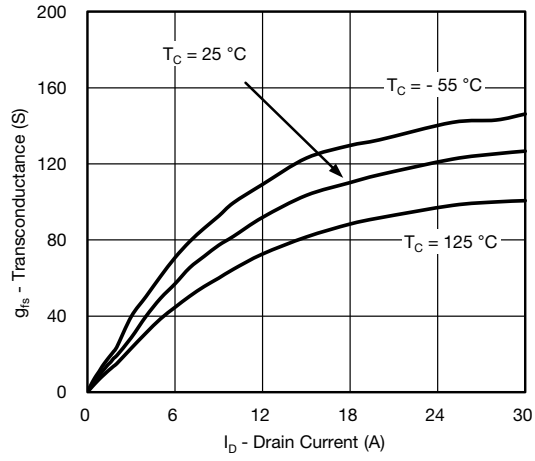
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



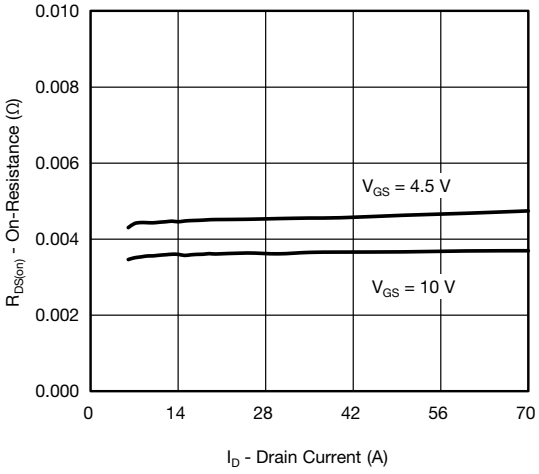
Output Characteristics



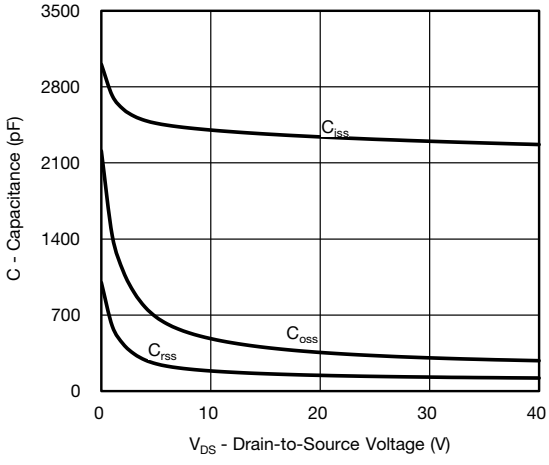
Transfer Characteristics



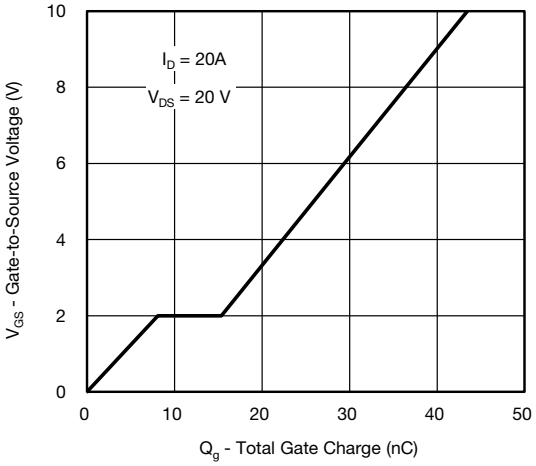
Transconductance



On-Resistance vs. Drain Current

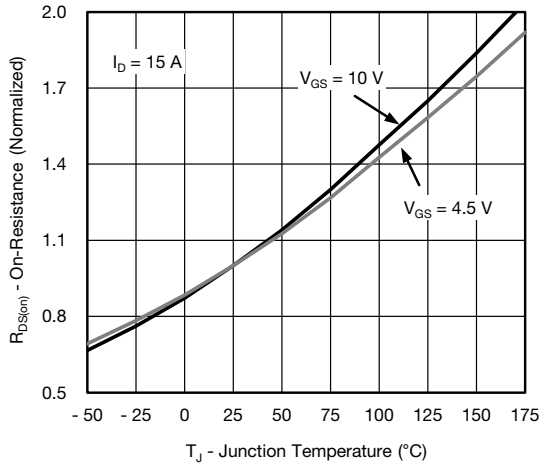


Capacitance

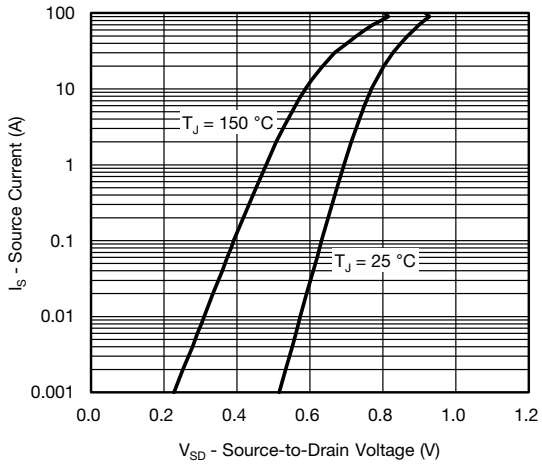


Gate Charge

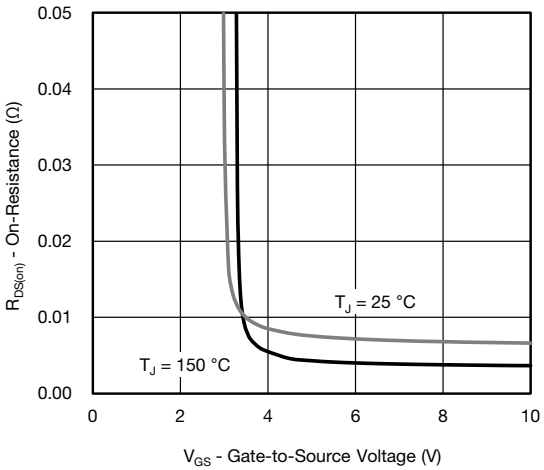
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



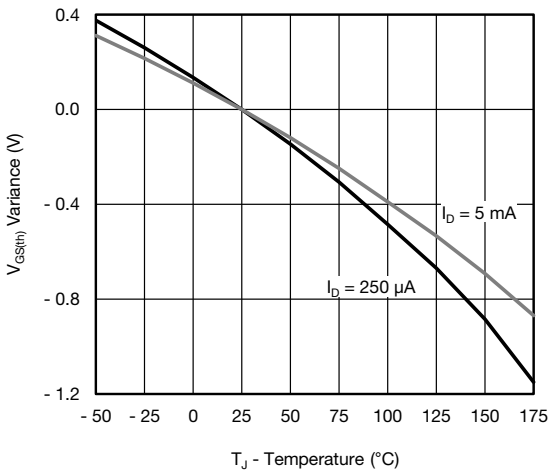
On-Resistance vs. Junction Temperature



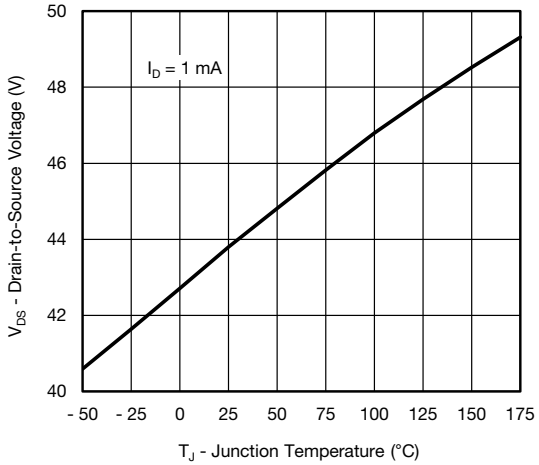
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage

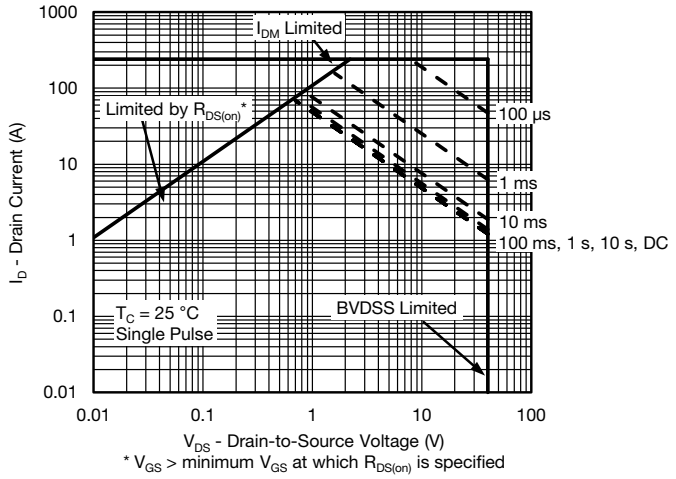


Threshold Voltage

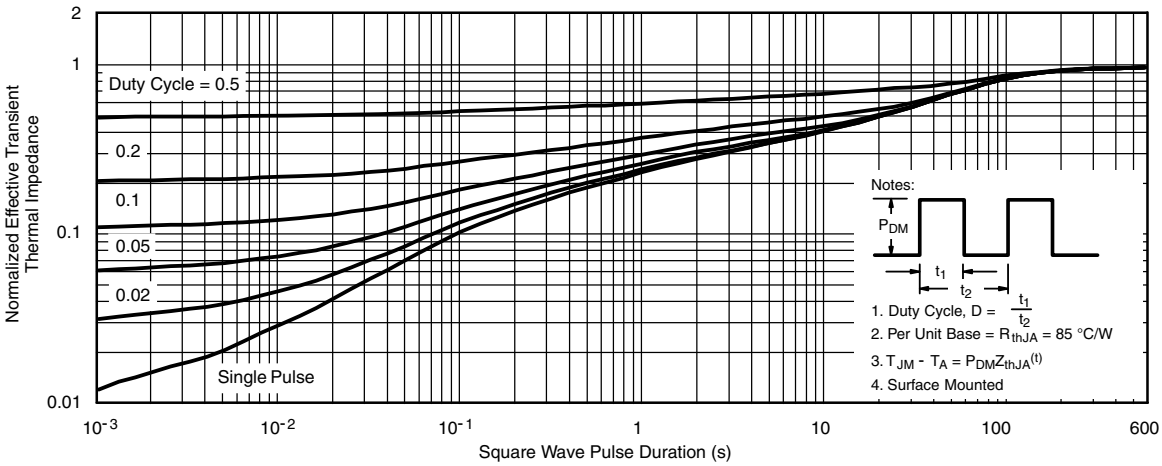


Drain Source Breakdown vs. Junction Temperature

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)

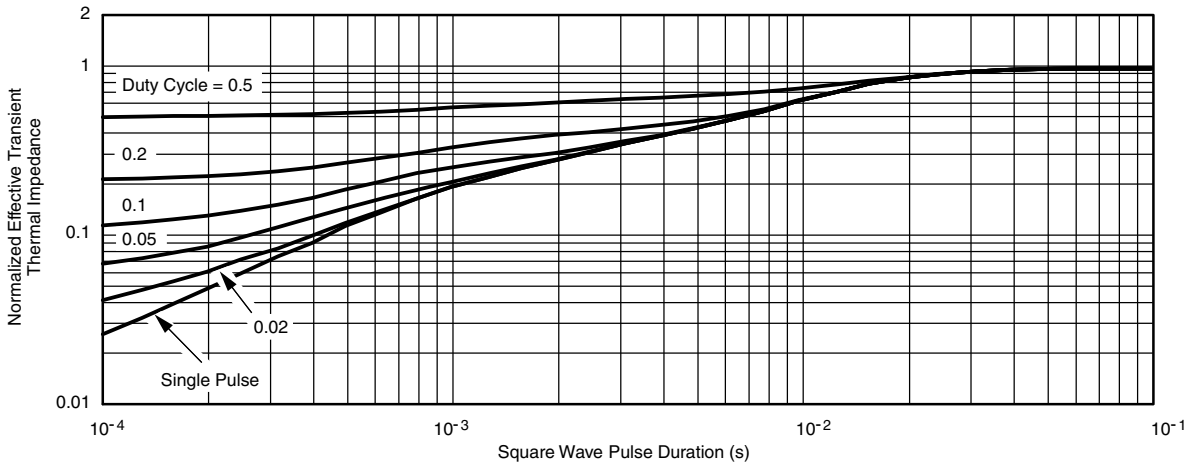


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Ambient

THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
  - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
  - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

  are given for general guidelines only to enable the user to get a “ball park” indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62790.

PowerPAK® SO-8L

Ordering codes for the SQ rugged series power MOSFETs in the PowerPAK SO-8L package:

DATASHEET PART NUMBER	OLD ORDERING CODE [a]	NEW ORDERING CODE
SQJ200EP	-	**SQJ200EP-T1_GE3**
SQJ401EP	SQJ401EP-T1-GE3	**SQJ401EP-T1_GE3**
SQJ402EP	SQJ402EP-T1-GE3	**SQJ402EP-T1_GE3**
SQJ403EEP	SQJ403EEP-T1-GE3	**SQJ403EEP-T1_GE3**
SQJ403EP	-	**SQJ403EP-T1_GE3**
SQJ410EP	SQJ410EP-T1-GE3	**SQJ410EP-T1_GE3**
SQJ412EP	SQJ412EP-T1-GE3	**SQJ412EP-T1_GE3**
SQJ422EP	SQJ422EP-T1-GE3	**SQJ422EP-T1_GE3**
SQJ431EP	SQJ431EP-T1-GE3	**SQJ431EP-T1_GE3**
SQJ443EP	SQJ443EP-T1-GE3	**SQJ443EP-T1_GE3**
SQJ456EP	SQJ456EP-T1-GE3	**SQJ456EP-T1_GE3**
SQJ460AEP	-	**SQJ460AEP-T1_GE3**
SQJ461EP	SQJ461EP-T1-GE3	**SQJ461EP-T1_GE3**
SQJ463EP	SQJ463EP-T1-GE3	**SQJ463EP-T1_GE3**
SQJ465EP	SQJ465EP-T1-GE3	**SQJ465EP-T1_GE3**
SQJ469EP	SQJ469EP-T1-GE3	**SQJ469EP-T1_GE3**
SQJ486EP	SQJ486EP-T1-GE3	**SQJ486EP-T1_GE3**
SQJ488EP	SQJ488EP-T1-GE3	**SQJ488EP-T1_GE3**
SQJ500AEP	SQJ500AEP-T1-GE3	**SQJ500AEP-T1_GE3**
SQJ840EP	SQJ840EP-T1-GE3	**SQJ840EP-T1_GE3**
SQJ844AEP	SQJ844AEP-T1-GE3	**SQJ844AEP-T1_GE3**
SQJ850EP	SQJ850EP-T1-GE3	**SQJ850EP-T1_GE3**
SQJ858AEP	SQJ858AEP-T1-GE3	**SQJ858AEP-T1_GE3**
SQJ886EP	SQJ886EP-T1-GE3	**SQJ886EP-T1_GE3**
SQJ910AEP	SQJ910AEP-T1-GE3	**SQJ910AEP-T1_GE3**
SQJ912AEP	SQJ912AEP-T1-GE3	**SQJ912AEP-T1_GE3**
SQJ940EP	SQJ940EP-T1-GE3	**SQJ940EP-T1_GE3**
SQJ942EP	SQJ942EP-T1-GE3	**SQJ942EP-T1_GE3**
SQJ951EP	SQJ951EP-T1-GE3	**SQJ951EP-T1_GE3**
SQJ952EP	-	**SQJ952EP-T1_GE3**
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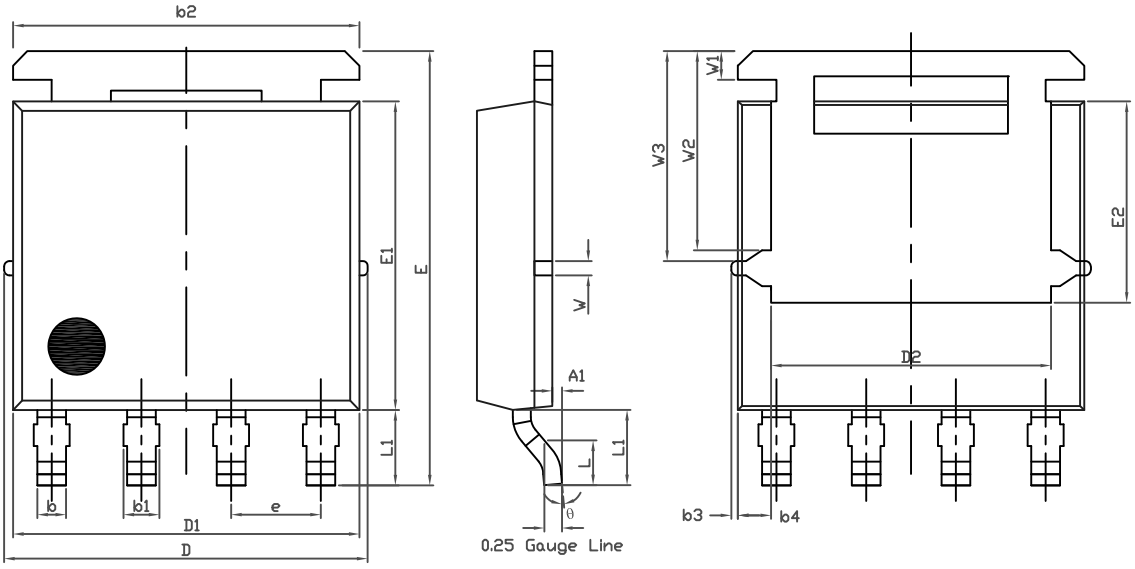
SQJ963EP	SQJ963EP-T1-GE3	**SQJ963EP-T1_GE3**
SQJ968EP	SQJ968EP-T1-GE3	**SQJ968EP-T1_GE3**
SQJ980AEP	SQJ980AEP-T1-GE3	**SQJ980AEP-T1_GE3**
SQJ992EP	SQJ992EP-T1-GE3	**SQJ992EP-T1_GE3**

Note

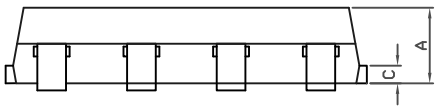
a. Old ordering code is obsolete and no longer valid for new orders

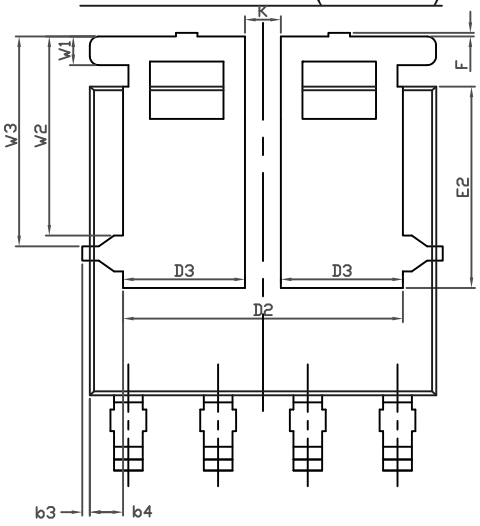
PowerPAK® SO-8L Case Outline for all Parts



TOPSIDE VIEW

BACKSIDE VIEW(SINGLE)





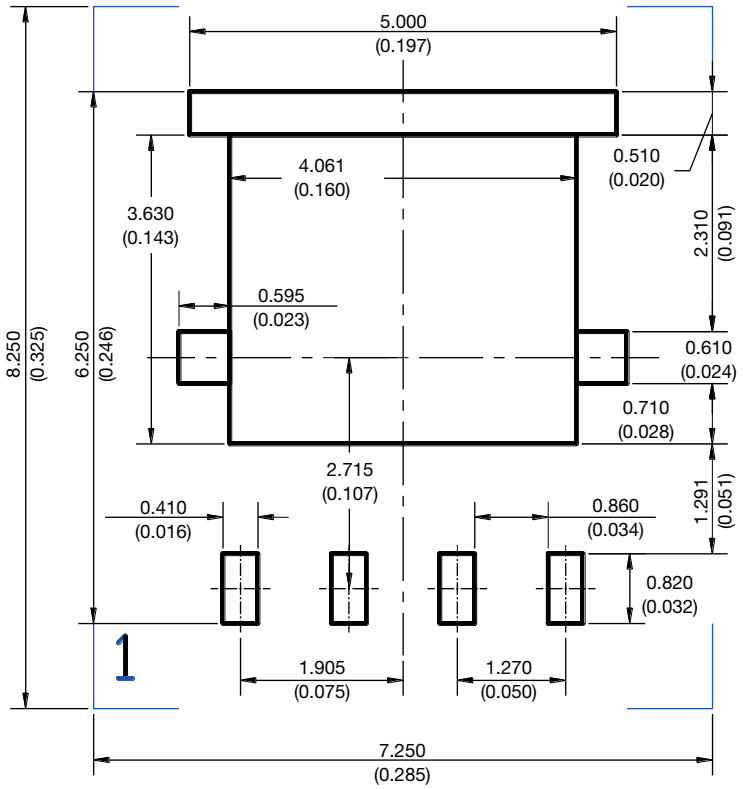
BACKSIDE VIEW(DUAL)

DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	1.00	1.07	1.14	0.039	0.042	0.045
A1	0.00	-	0.127	0.00	-	0.005
b	0.33	0.41	0.48	0.013	0.016	0.019
b1	0.44	0.51	0.58	0.017	0.020	0.023
b2	4.80	4.90	5.00	0.189	0.193	0.197
b3	0.094			0.004		
b4	0.47			0.019		
c	0.20	0.25	0.30	0.008	0.010	0.012
D	5.00	5.13	5.25	0.197	0.202	0.207
D1	4.80	4.90	5.00	0.189	0.193	0.197
D2	3.86	3.96	4.06	0.152	0.156	0.160
D3	1.63	1.73	1.83	0.064	0.068	0.072
e	1.27 BSC			0.050 BSC		
E	6.05	6.15	6.25	0.238	0.242	0.246
E1	4.27	4.37	4.47	0.168	0.172	0.176
E2	2.75	2.85	2.95	0.108	0.112	0.116
F	-	-	0.15	-	-	0.006
L	0.62	0.72	0.82	0.024	0.028	0.032
L1	0.92	1.07	1.22	0.036	0.042	0.048
K	0.51			0.020		
W	0.23			0.009		
W1	0.41			0.016		
W2	2.82			0.111		
W3	2.96			0.117		
q	0°	-	10°	0°	-	10°
ECN: C15-1203-Rev. A, 07-Sep-15 DWG: 6044						

Note

- Millimeters will gover

RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads
Dimensions in mm (inches)

Disclaimer

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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.